

MSC2712GT1G, MSC2712YT1G

General Purpose Amplifier Transistor

NPN Surface Mount

Features

- Moisture Sensitivity Level: 1
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	60	Vdc
Collector-Emitter Voltage	$V_{(BR)CEO}$	50	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	7.0	Vdc
Collector Current – Continuous	I_C	100	mAdc
Collector Current – Peak	$I_{C(P)}$	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



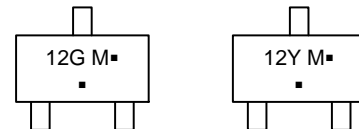
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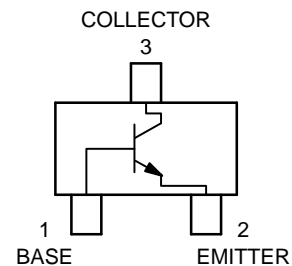


SC-59
CASE 318D
STYLE 1

MARKING DIAGRAMS



12M, 12Y = Specific Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)



ORDERING INFORMATION

Device	Package	Shipping†
MSC2712GT1G	SC-59 (Pb-Free)	3000 / Tape & Reel
MSC2712YT1G	SC-59 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSC2712GT1G, MSC2712YT1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Breakdown Voltage (I _C = 2.0 mA, I _B = 0)	V _{(BR)CEO}	50	–	Vdc
Collector–Base Breakdown Voltage (I _C = 10 μA, I _E = 0)	V _{(BR)CBO}	60	–	Vdc
Emitter–Base Breakdown Voltage (I _E = 10 μA, I _C = 0)	V _{(BR)EBO}	7.0	–	Vdc
Collector–Base Cutoff Current (V _{CB} = 45 Vdc, I _E = 0)	I _{CBO}	–	0.1	μA
Collector–Emitter Cutoff Current (V _{CE} = 10 Vdc, I _B = 0) (V _{CE} = 30 Vdc, I _B = 0) (V _{CE} = 30 Vdc, I _B = 0, T _A = 80°C)	I _{CEO}	– – –	0.1 2.0 1.0	μA μA mA
DC Current Gain (Note 1) (V _{CE} = 6.0 Vdc, I _C = 2.0 mA)	h _{FE}			–
		200 120	400 240	
Collector–Emitter Saturation Voltage (I _C = 100 mA, I _B = 10 mA)	V _{CE(sat)}	–	0.5	Vdc
Current – Gain – Bandwidth Product (I _C = 1 mA, V _{CE} = 10.0 V, f = 10 MHz)	f _T	50	–	MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.

TYPICAL ELECTRICAL CHARACTERISTICS

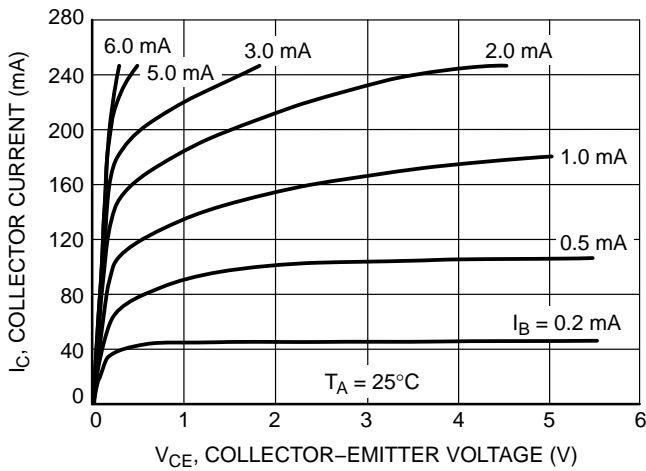


Figure 1. Collector Saturation Voltage

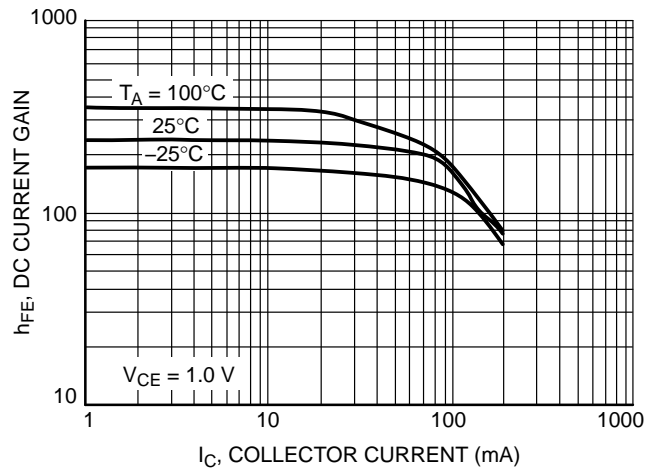


Figure 2. DC Current Gain

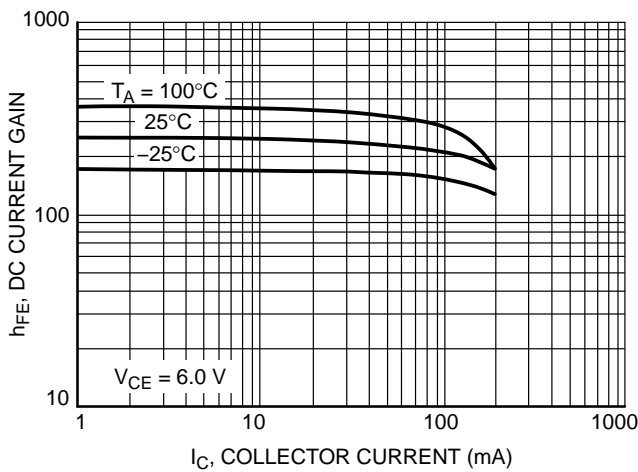


Figure 3. DC Current Gain

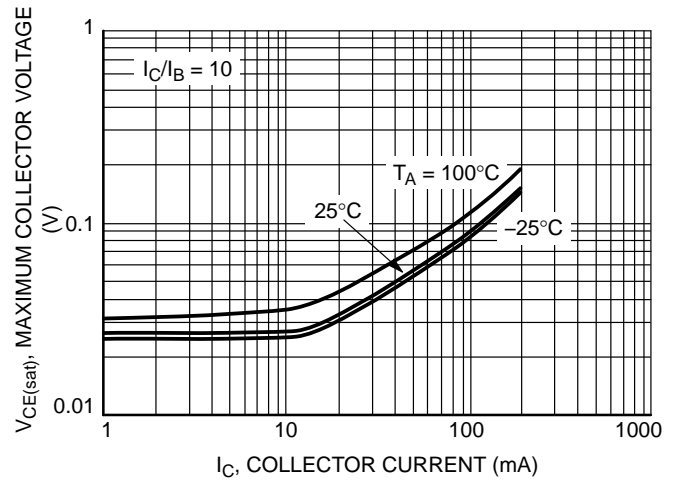


Figure 4. $V_{CE(sat)}$ versus I_C

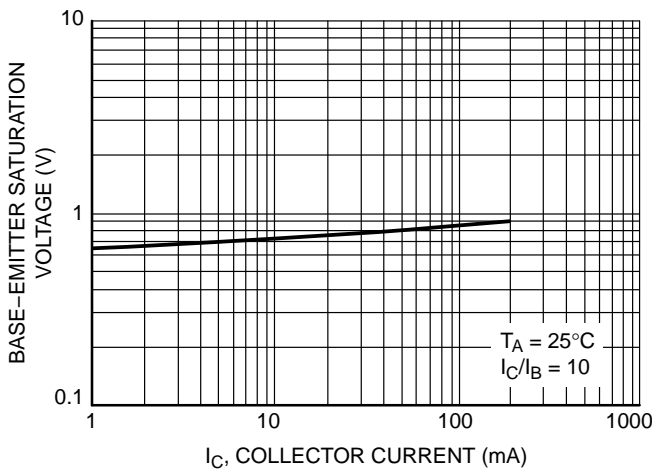


Figure 5. $V_{BE(sat)}$ versus I_C

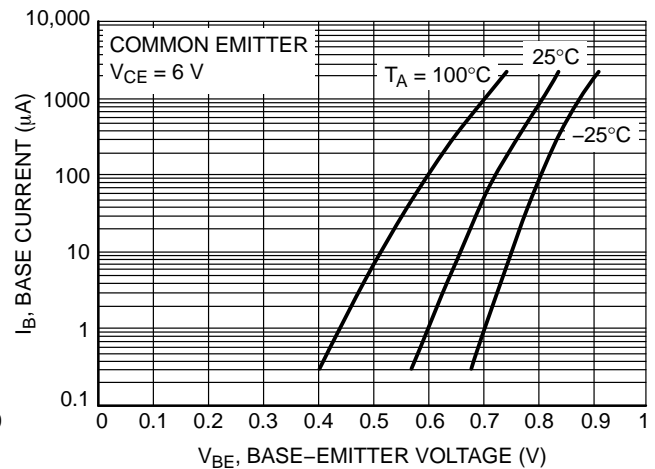


Figure 6. Base-Emitter Voltage

MSC2712GT1G, MSC2712YT1G

TYPICAL ELECTRICAL CHARACTERISTICS

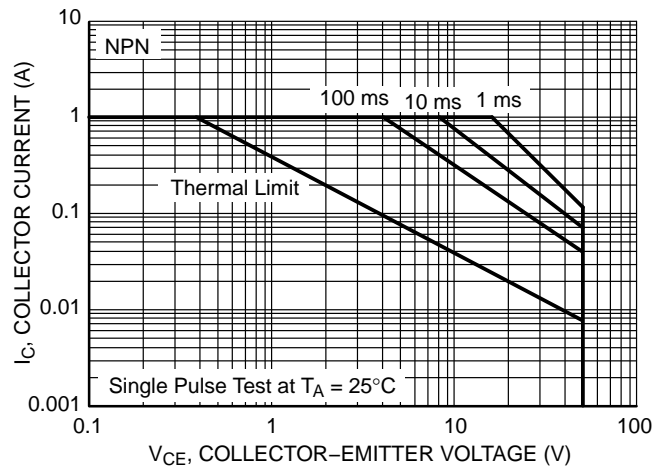


Figure 7. NPN Safe Operating Area

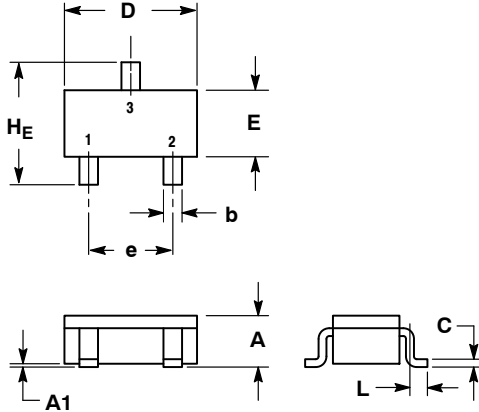
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



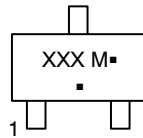
SCALE 2:1

SC-59
CASE 318D-04
ISSUE H

DATE 28 JUN 2012



GENERIC MARKING DIAGRAM*



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package*

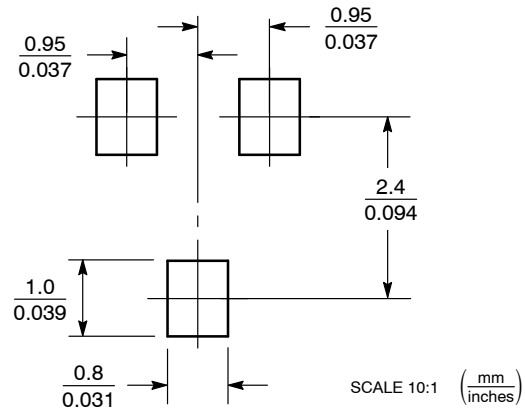
(*Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|-----------------------------------------------------------------|----------------------------------------------------------------|----------------------------------------------------------------------|
| <p>STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR</p> | <p>STYLE 2:
PIN 1. ANODE
2. N.C.
3. CATHODE</p> | <p>STYLE 3:
PIN 1. ANODE
2. ANODE
3. CATHODE</p> |
| <p>STYLE 4:
PIN 1. CATHODE
2. N.C.
3. ANODE</p> | <p>STYLE 5:
PIN 1. CATHODE
2. CATHODE
3. ANODE</p> | <p>STYLE 6:
PIN 1. ANODE
2. CATHODE
3. ANODE/CATHODE</p> |

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